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PN4275

FAIRCHILD SEMICONDUCTOR TM

PN4275



NPN Switching Transistor

This device is designed for high speed saturated switching applications at currents to 100 mA. Sourced from Process 21. See PN2369A for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V_{CEO}	Collector-Emitter Voltage	15	V	
V _{CBO}	Collector-Base Voltage	40	V	
V_{EBO}	Emitter-Base Voltage	4.5	V	
I _C	Collector Current - Continuous	200	mA	
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristi

stics	TA = 25°C unless otherwise noted	

Symbol	Characteristic	Max	Units
		PN4275	-
P _D	Total Device Dissipation Derate above 25°C	350 2.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	357	°C/W

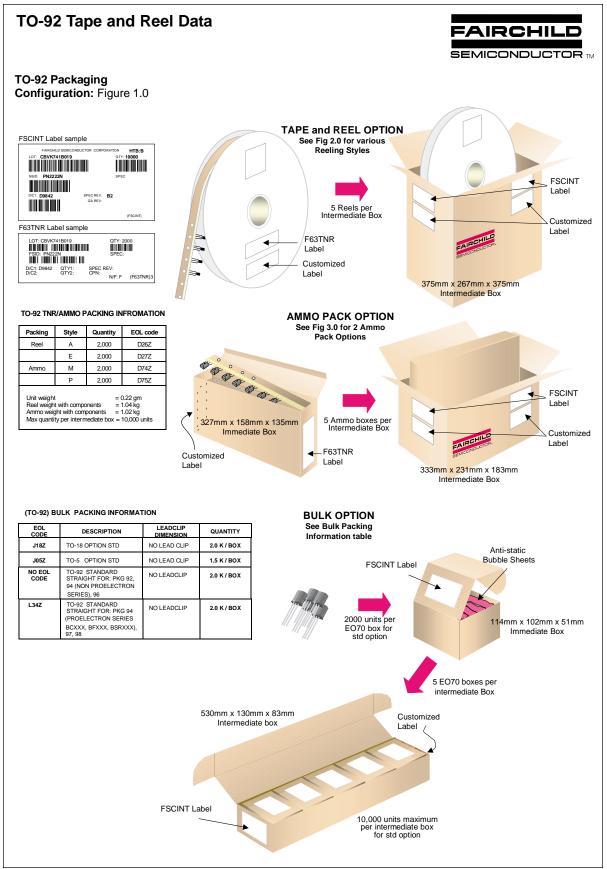
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NPN Switching Transistor

Electr	ical Characteristics TA	= 25°C unless otherwise noted			
Symbol	Parameter	Test Conditions	Min	Max	Units
	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	15		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \mu {\rm A}, I_{\rm E} = 0$	40		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$	4.5		V
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 10 \mu{\rm A}, I_{\rm B} = 0$	40		V
I _B	Base Cutoff Current	$V_{CE} = 20 \text{ V}$		0.4	μA
Сво	Collector Cutoff Current	$V_{CB} = 20 \text{ V}, \text{ I}_E = 0,$ $T_A = 65 \text{ °C}$		10	μA
h _{FE}	DC Current Gain	$ I_{C} = 10 \text{ mA}, V_{CE} = 1.0 \text{ V} \\ I_{C} = 30 \text{ mA}, V_{CE} = 0.4 \text{ V} \\ I_{C} = 100 \text{ mA}, V_{CE} = 1.0 \text{ V} $	35 30 18	120	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$ \begin{array}{l} I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} = 30 \text{ mA}, I_{B} = 3.0 \text{ mA} \\ I_{C} = 10 \text{ mA}, I_{B} = 3.3 \text{ mA} \\ I_{C} = 100 \text{ mA}, I_{B} = 10 \text{ mA} \\ I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA}, \end{array} $		0.20 0.25 0.18 0.50	V V V V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$\begin{array}{l} T_{A} = 65 \ ^{\circ}\text{C} \\ I_{C} = 10 \ \text{mA}, I_{B} = 1.0 \ \text{mA} \\ I_{C} = 30 \ \text{mA}, I_{B} = 3.0 \ \text{mA} \\ I_{C} = 10 \ \text{mA}, I_{B} = 3.3 \ \text{mA} \\ I_{C} = 100 \ \text{mA}, I_{B} = 10 \ \text{mA} \end{array}$	0.72	0.30 0.85 1.15 1.0 1.6	V V V V V
SMALL S	IGNAL CHARACTERISTICS	• • • • •			
C _{ob}	Output Capacitance	$V_{CB} = 5.0 \text{ V}, \text{ f} = 1.0 \text{ MHz}$		4.0	pF
Դfe	Small-Signal Current Gain	$I_{c} = 10 \text{ mA}, V_{cE} = 10 \text{ V},$ f = 100 MHz	4.0		
SWITCHI	NG CHARACTERISTICS				
t _{on}	Turn-on Time	$V_{CC} = 3.0 \text{ V}, I_{C} = 10 \text{ mA},$		12	ns
d	Delay Time	I _{B1} = 3.3 mA,		9.0	ns
	-		L	1	1

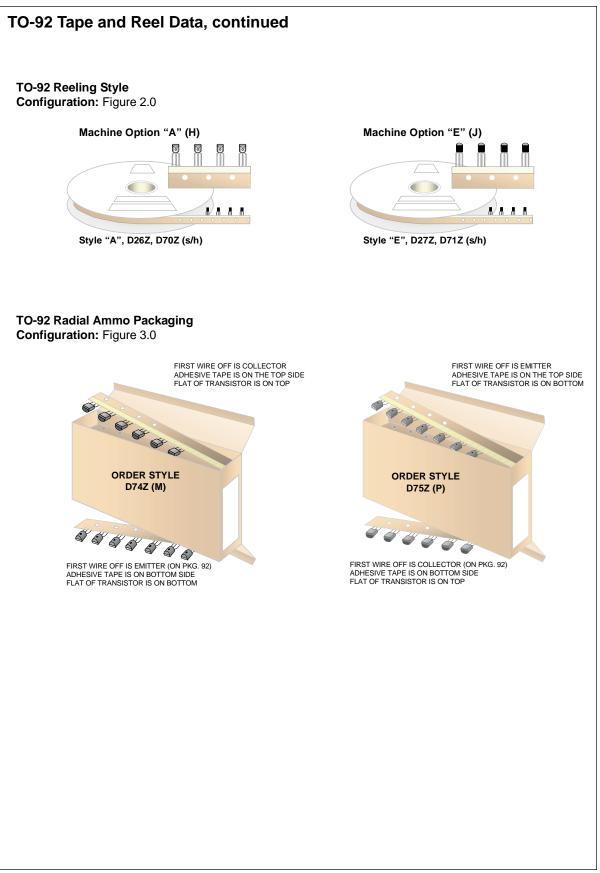
t _{on}	Turn-on Time	$V_{CC} = 3.0 \text{ V}, I_C = 10 \text{ mA},$	12	ns
t _d	Delay Time	I _{B1} = 3.3 mA,	9.0	ns
tr	Rise Time	VBE (off) = -3.0 V	7.0	ns
t _{off}	Turn-off Time	$V_{CC} = 3.0 \text{ V}, I_C = 10 \text{ mA}$	12	ns
ts	Storage Time	$I_{B1} = I_{B2} = 3.3 \text{ mA}$	8.0	ns
t _f	Fall Time	$V_{BE (off)} = -3.0 V$	8.0	ns
ts	Storage Time	$I_{\rm C} = I_{\rm B1} = I_{\rm B2} = 10 \text{ mA}$	13	ns

*Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%



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PRODUCT STATUS DEFINITIONS

Definition of Terms

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